

UNR92AFG

Silicon NPN epitaxial planar type

For digital circuits

■ Features

- Optimum for high-density mounting and downsizing of the equipment
- Contribute to low power consumption

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

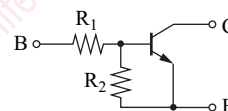
| Parameter | Symbol | Rating | Unit |
|---------------------------------------|------------------|-------------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | 50 | V |
| Collector-emitter voltage (Base open) | V_{CEO} | 50 | V |
| Collector current | I_{C} | 80 | mA |
| Total power dissipation | P_{T} | 125 | mW |
| Junction temperature | T_{j} | 125 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +125 | $^\circ\text{C}$ |

■ Package

- Code
SSMini3-F3
- Pin Name
1: Base
2: Emitter
3: Collector

■ Marking Symbol: KD

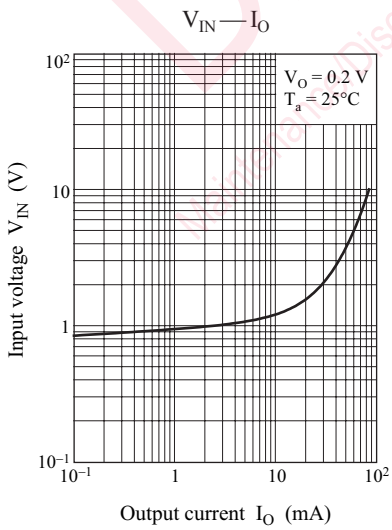
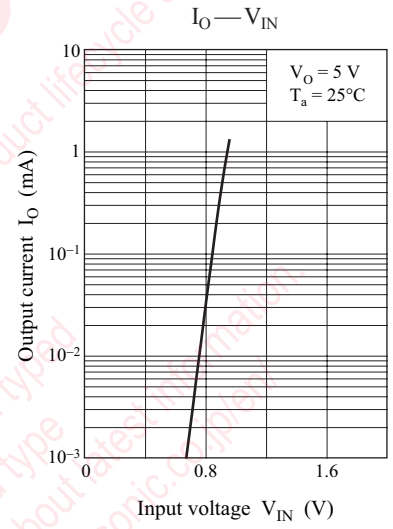
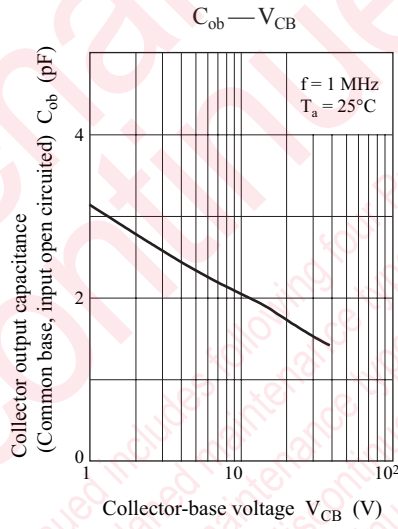
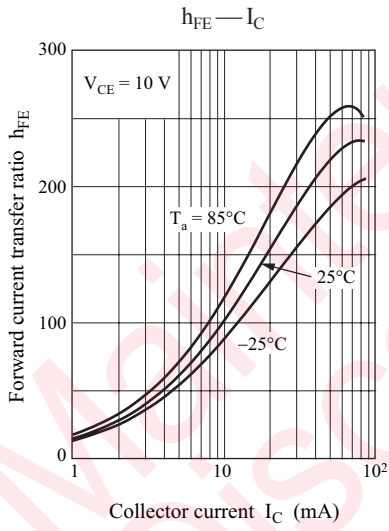
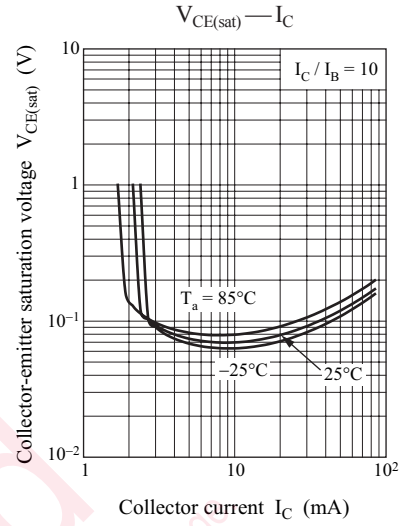
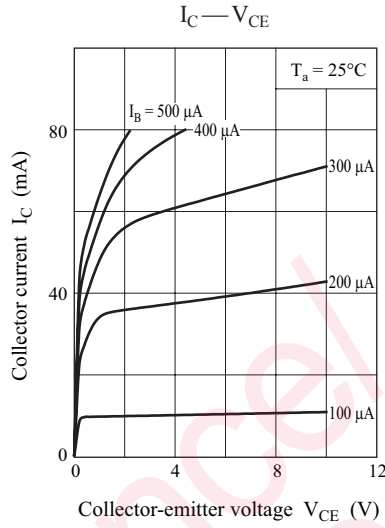
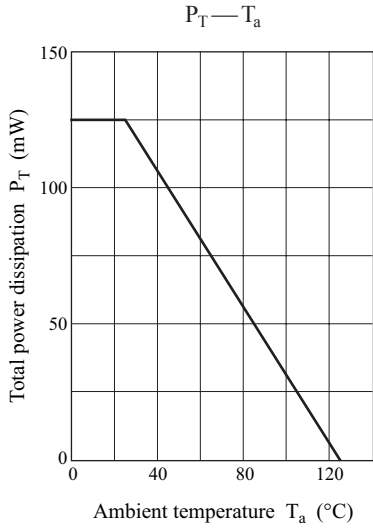
■ Internal Connection



■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

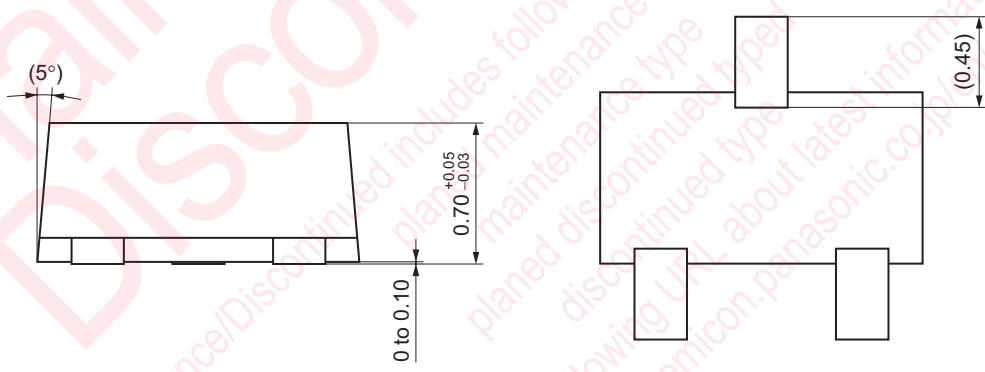
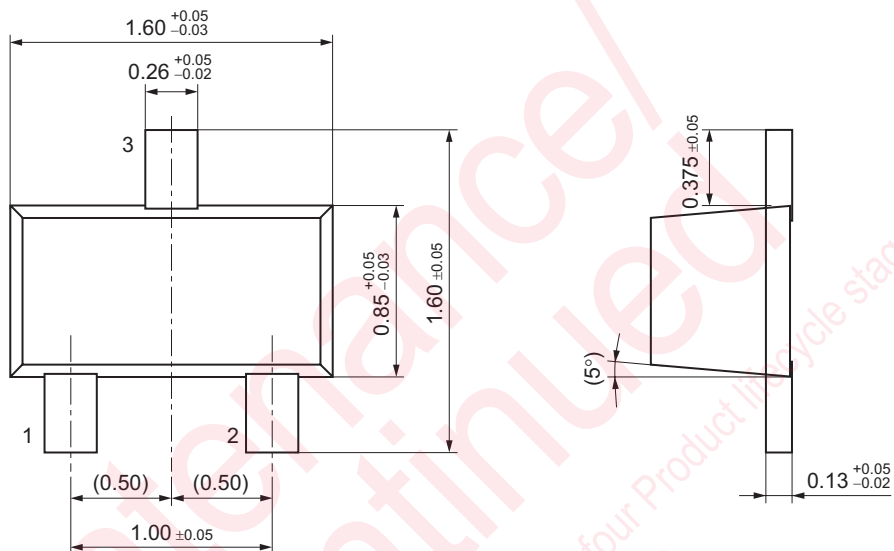
| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|--|-------------------------------|---|------|------|------|------------------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_{\text{C}} = 10 \mu\text{A}, I_{\text{E}} = 0$ | 50 | | | V |
| Collector-emitter voltage (Base open) | V_{CEO} | $I_{\text{C}} = 2 \text{ mA}, I_{\text{B}} = 0$ | 50 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{\text{CB}} = 50 \text{ V}, I_{\text{E}} = 0$ | | | 0.1 | μA |
| Collector-emitter cutoff current (Base open) | I_{CEO} | $V_{\text{CE}} = 50 \text{ V}, I_{\text{B}} = 0$ | | | 0.5 | μA |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{\text{EB}} = 6 \text{ V}, I_{\text{C}} = 0$ | | | 1.0 | mA |
| Forward current transfer ratio | h_{FE} | $V_{\text{CE}} = 10 \text{ V}, I_{\text{C}} = 5 \text{ mA}$ | 30 | | | — |
| Collector-emitter saturation voltage | $V_{\text{CE(sat)}}$ | $I_{\text{C}} = 10 \text{ mA}, I_{\text{B}} = 0.3 \text{ mA}$ | | | 0.25 | V |
| Output voltage high-level | V_{OH} | $V_{\text{CC}} = 5 \text{ V}, V_{\text{B}} = 0.5 \text{ V}, R_{\text{L}} = 1 \text{ k}\Omega$ | 4.9 | | | V |
| Output voltage low-level | V_{OL} | $V_{\text{CC}} = 5 \text{ V}, V_{\text{B}} = 2.5 \text{ V}, R_{\text{L}} = 1 \text{ k}\Omega$ | | | 0.2 | V |
| Input resistance | R_{I} | | -30% | 4.7 | +30% | $\text{k}\Omega$ |
| Resistance ratio | $R_{\text{I}} / R_{\text{2}}$ | | 0.37 | 0.47 | 0.57 | — |
| Transition frequency | f_{T} | $V_{\text{CB}} = 10 \text{ V}, I_{\text{E}} = -2 \text{ mA}, f = 200 \text{ MHz}$ | | 150 | | MHz |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.



SSMini3-F3

Unit: mm



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